### MLX91208

## IMC-Hall<sup>®</sup> Current Sensor (Triaxis<sup>®</sup> Technology)

#### **Features and Benefits**

- ☐ Programmable high speed current sensor
- □ Tria⊗is® Technology
- ☐ Very high sensitivity due to Integrated Magnetic Concentrator (IMC-Hall®)
- ☐ Wideband: DC to 200kHz
- ☐ Very short response time: 3µs
- ☐ Programmable linear transfer characteristic
- ☐ Selectable analog ratiometric output
- ☐ SO-8 package, RoHS compliant
- ☐ Lead free component, suitable for lead free soldering profile 260°C (target), MSL3

#### **Application Examples**

- Inverter HEV and EV
- BLDC motor current monitoring
- ☐ Smart fuse (over-current detection)
- □ AC/DC Converter
- □ DC/AC Converter (Inverter)
- □ DC/DC switched mode power supply

#### **Ordering Information**

Part No.	Temperature Code	Package	Option code	Packing Form	Sensitivity Range (Default)
MLX91208	L (-40°C to 150°C)	DC (SOIC)	CAL-000 (low field)	TU/RE (tube/reel)	100-700mV/mT (250mV/mT)
MLX91208	L (-40°C to 150°C)	DC (SOIC)	CAH-000 (high field)	TU/RE (tube/reel)	50-300mV/mT (100mV/mT)
MLX91208	L (-40°C to 150°C)	DC (SOIC)	CAV-000 (v. high f.)	TU/RE (tube/reel)	30-200mV/mT (40mV/mT)
MLX91208	L (-40°C to 150°C)	DC (SOIC)	CAV-001 (v. high f.)	TU/RE (tube/reel)	30-200mV/mT (60mV/mT)

Ordering example: MLX91208LDC-CAH-000-RE

### 1 Functional Diagram

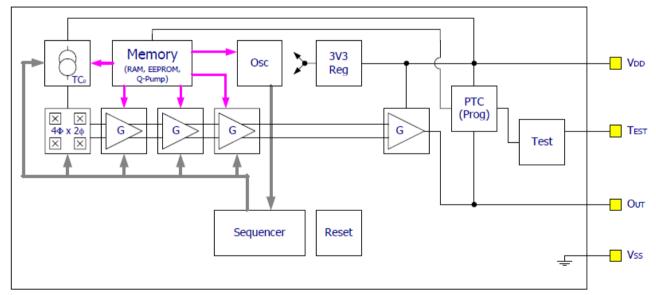


Figure 1: Block diagram



#### 2 General Description

The MLX91208 is a monolithic sensor IC featuring the Tria⊗is™ Hall technology. Conventional planar Hall technology is only sensitive to the flux density applied orthogonally to the IC surface. The IMC-Hall® current sensor is sensitive to the flux density applied parallel to the IC surface. This is obtained through an Integrated Magneto-Concentrator (IMC-Hall®) which is deposited on the CMOS die (as an additional back-end step). The IMC-Hall® technology is automotive qualified.

The product is a single chip Hall sensor which provides an output signal proportional to the flux density applied horizontally and is therefore suitable for current measurement. It is ideally suited as an open loop current sensor for PCB or bus bar mounting. It features small size application design and a simple construction for various current ranges from few Amperes up to 1000 Amperes.

The transfer characteristic of the MLX91208 is programmable in terms of offset, gain or temperature compensation. The linear analog output is designed for applications where a very fast response is required, such as inverter applications.

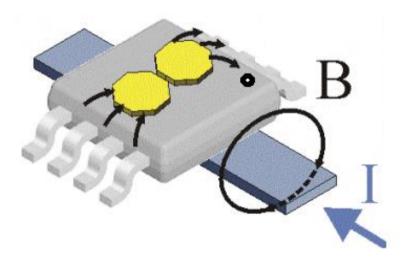


Figure 2: Typical application of MLX91208 (magnetic field generated by the current).





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### 3 Glossary of Terms

ADC Analog to Digital Converter
DAC Digital to Analog Converter
DNL Differential Non Linearity

IMC Integrated Magneto Concentrator (IMC-Hall®)

INL Integral Non Linearity
LSB Least Significant Bit
MSB Most Significant Bit
NC Not Connected

PTC Programming Through Connector TC Temperature Coefficient in ppm/°C

Tesla Units for the magnetic flux density, 1 mT = 10 Gauss

#### 4 Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Positive Supply Voltage (overvoltage)	Vdd	+10	V
Reverse Supply Voltage Protection		-0.3	V
Positive Output Voltage (1)		+10	V
Output Current	lout	±70	mA
Reverse Output Voltage		-0.3	V
Reverse Output Current		-50	mA
Package Thermal Resistance	Rth	105	°C/W
Operating Ambient Temperature Range	T <sub>A</sub>	-40 to +150	°C
Storage Temperature Range	Ts	-55 to +165	°C
Magnetic Flux Density		infinite	Т

Table 1: Absolute maximum ratings

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

(1) Valid for supply=10V or supply-pin floating

### 5 Pin Definitions and Descriptions

Pin #	Name	Туре	Function
1	VDEC	Digital	Digital Supply Voltage
3	VSS	Ground	Supply Voltage
4	TEST/MUST	Digital	Test and Factory Calibration
5	VDD	Supply	Supply Voltage
6	OUT	Analog	Current Sensor Output

Table 2: Pin definition and description

It is recommended to connect unused pins to the Ground for optimal EMC results.



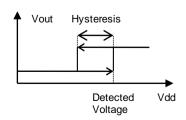
### 6 General Electrical Specifications

Operating Parameters:  $T_A = -40^{\circ}\text{C}$  to 125°C, Vdd = 4.5V to 5.5V, lout = -2mA to +2mA, recommended application diagram in section 1, unless otherwise specified. All mentioned component values can have a  $\pm 20\%$  tolerance.

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Nominal Supply Voltage	Vdd		4.5	5	5.5	V
Supply Current	ldd	Without output load In application mode TA = -40°C to 150°C	7	12	14	mA
DC Load Current	lout	R <sub>load</sub> in range [6kΩ, 100kΩ]	-2		2	mΑ
Maximum Output Current (driving capability)	lmax	Inside this range, output voltage reaches 3%Vdd and 97%Vdd	-2		2	mA
Output Resistance		Vout = $50\%$ Vdd, $R_L = 10k\Omega$		1	5	Ω
Output Capacitive Load	C <sub>load</sub>	Capacitive load range for the stability of the output amplifier. Output amplifier optimized for the typical capacitive load.	1	2	10	nF
Output Resistive Load	R <sub>load</sub>	Output resistive load for high linearity (both pull-up and pull-down resistor)	6			kΩ
Output Short Circuit Current		Output shorted to Vdd (Permanent)	35		180	mΑ
Output Short Circuit Current	Ishort	Output shorted to Vss (Permanent)	35		180	mΑ
Output Leakage current	lleak	High impedance mode (1) T = 150°C	0.5	1.5	20	uA
Output Voltage Swing	$V_{out\_pd}$	pull down ≥ 10 kΩ	10		90	%Vdd
(Linear Range)	V <sub>out_pu</sub>	pull up ≥ 10 kΩ	10		90	%Vdd
Lligh insured on some deleviste (1)	$V_{out\_HiZ\_pu}$	pull-up R <sub>L</sub> ≤ 25 kΩ, T≤125°C	95			%Vdd
High-impedance mode levels (1)	$V_{out\_HiZ\_pd}$	pull-down $R_L \le 25 \text{ k}\Omega$ , $T \le 125 ^{\circ}\text{C}$			5	%Vdd
Under voltage detection (2)	$V_{dd\_uvd}$	Low to High Voltage	3	3.3	4	V
Under-voltage detection (2)	$V_{dd\_uvh}$	Hysteresis	0.25	0.3	0.4	V
Over veltere detection (2)	$V_{dd\_ovd2}$	Low to High Voltage	6.7		7.6	V
Over-voltage detection (2)	V <sub>dd_ov h2</sub>	Hysteresis	0.05		0.7	V
Defensely analysis dates (2)	V <sub>ratio_d</sub>	Low to High Voltage	4		4.45	V
Ratiometry enable detection (2)	V <sub>ratio_h</sub>	Hysteresis	0.05		0.5	V

Table 3: General electrical parameter

- (1) Refer to chapter Self diagnostic, Table 10.
- (2) According to figure on the right:





### 7 Magnetic specification

Operating Parameters  $T_A = -40$ °C to 125°C, Vdd = 4.5V to 5.5V, unless otherwise specified.

#### 7.1 Low Field Version 10mT (marking xxL)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Nominal Magnetic field range	Bnom		-7.5		+7.5	mT
Operational Field Range (1)	Вор		-10		+10	mΤ
Linearity Error	NL	B in range Bop Vout in [10%Vdd, 90%Vdd]	-0.7		+0.7	%FS
Hysteresis	Br	B = Bop	-10		+10	uT
Programmable Sensitivity	S		100	250	700	mV/mT
Sensitivity programming Resolution	Sres			0.1		%

Table 4: Magnetic specification for 10mT version (low field)

#### 7.2 High Field Version 25mT (marking xxH)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Nominal Magnetic field range	Bnom		-20		+20	mT
Operational Field Range (1)	Вор		-25		+25	mT
Linearity Error	NL	B in range Bop Vout in [10%Vdd, 90%Vdd]	-0.7		+0.7	%FS
Hysteresis	Br	B = Bop	-25		+25	uT
Programmable Sensitivity	S		50	100	300	mV/mT
Sensitivity programming Resolution	Sres			0.1		%

Table 5: Magnetic specification for 25mT version (high field)

#### 7.3 Very High Field Version 60mT (marking xxV)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Nominal Magnetic field range	Bnom		-50		+50	mΤ
Operational Field Range (1)	Вор		-60		+60	mΤ
Linearity Error	NL	B in range Bop Vout in [10%Vdd, 90%Vdd]	-0.7		+0.7	%FS
Hysteresis	Br	B = Bop	-50		+50	uT
Programmable Sensitivity	S	CAV-000 CAV-001	30 30	40 60	200 200	mV/mT mV/mT
Sensitivity programming Resolution	Sres			0.1		%

Table 6: Magnetic specification for 60mT version (very high field)

(1) Outside Bop, the IMC progressively enters saturation, yielding to an increase of the linearity error.

### 8 Analog output specification

#### 8.1 Timing specification

Operating Parameters  $T_A = -40$ °C to 125°C, Vdd = 4.5V to 5.5V (unless otherwise specified).

Parameter	Symbol	Test Conditions / Comments	Min	Тур	Max	Units
Refresh rate	Trr		0.8	1	2	μs
Step Response Time	Tresp	Delay between the input signal reaching 90% and the output signal reaching 90%, (2V step at the output, input rise time = 1µs) -Noise filter OFF -Noise filter ON		3 5	4 6	μs μs
Bandwidth	BW	-Noise filter OFF -Noise filter ON	200 120	250 150	300 180	kHz kHz
Power on Delay	T <sub>POD</sub>	Vout =100% of FS Pull-down resistor ≤100kOhm During the Power-on delay, the output will remain within the 10% fault band at all time.			1	ms
Ratiometry Cut-off Frequency	Fratio			250		Hz

Table 7: Timing specification for high speed analog output

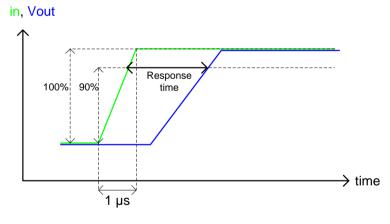


Figure 4: Response time definition



#### 8.2 Accuracy specification

Operating Parameters  $T_A = -40$ °C to 125°C, Vdd = 4.5V to 5.5V (unless otherwise specified).

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Thermal Offset Drift	Δ <sup>T</sup> Voq	Offset drift referred to 25°C S=40mV/mT (xxV version) S=100mV/mT (xxH version) S=250mV/mT (xxL version) Vdd=5V TC=0±150 ppm/°C Voq=50±0.2 %Vdd	-10		+10	mV
Thermal Offset Drift Resolution	Δ <sup>T</sup> VoqRes			0.075		mV/°C
Thermal Sensitivity Drift	TC		-1.5	0	+1.5	% of S
Thermal Sensitivity Drift Resolution	TCres			40		ppm/°C
RMS Output noise	N <sub>rms</sub>	S=40mV/mT (xxV version) S=100mV/mT (xxH version) S=250mV/mT (xxL version) -Noise filter OFF -Noise filter ON			0.2 0.12	%Vdd %Vdd
Ratiometry Error Offset	ΔVoq	Voq = 50%Vdd $\Delta Vdd = 10\%Vdd$	-0.4		+0.4	% of Voq
Ratiometry Error Sensitivity	ΔS	ΔVdd = 10%Vdd	-0.4		+0.4	% of S

Table 8: Accuracy-Specific Parameters

#### 8.3 Remarks to the achievable accuracy

The achievable target accuracy depends on the user end of line calibration. The resolution for the offset and offset drift calibration is better than 0.1%Vdd. Trimming capability is higher than measurement accuracy. End user calibration can increase the accuracy of the system.



### 9 Programmable items

#### 9.1 Parameter table

Parameter	Bits	Comment
VOQ[11:0]	12	Quiescent output level (0 Gauss) adjustment
RG[2:0]	3	Rough gain adjustment
FG[9:0]	10	Fine gain adjustment
ENRATIO	1	Ratiometry enablement
TC1[7:0]	8	Adjustment of the first order temperature compensation of the magnetic sensitivity
TC2HOT[4:0]	5	Adjustment of the extra temperature compensation of the magnetic sensitivity at high temperature
TC2COLD[4:0]	5	Adjustment of the extra temperature compensation of the magnetic sensitivity at low temperature
OFFDR2C[5:0]	6	Adjustment of the offset drift at low temperature after the VGA
OFFDR2H[5:0]	6	Adjustment of the offset drift at high temperature after the VGA
NOISEFILT	1	Noise filter enablement
CRC[15:0]	16	16-bit CRC for the checksum calculation of the configuration register.
ID[47:0]	48	Customer identification code

Table 9: Customer programmable items

#### 9.2 Sensitivity programming (RG, FG)

The sensitivity can be programmed from 50 to 300mV/mT (high field version) or 100 to 700mV/mT (low field version), with the ROUGHGAIN (3 bits) and FINEGAIN (10 bits) parameters.

#### 9.3 Offset / output quiescent voltage programming (VOQ)

The offset is programmable with 12 bits in 1.5 mV steps over the full output range. This corresponds to a calibration resolution of 0.03 %VDD.

The typical step size would be 5V/4096 = 1.22 mV, but the actual step size can differ from the nominal value because of internal gain tolerance. A maximum step size of 1.5 mV is guaranteed.

Note: for optimal performance over temperature, the VOQ should be programmed in the range from 2 to 3V.

#### 9.4 Output ratiometry (ENRATIO)

The ratiometry of the output versus the supply can be disabled by setting this bit to 0.

**Note:** for optimal performance over temperature, the ratiometry setting should not be changed on customer side. By default, this setting is enabled during final test calibration.



#### 9.5 Sensitivity temperature drift programming (TC1ST, TC2ND\_COLD, TC2ND\_HOT)

First order sensitivity temperature drift can be trimmed with TC1. The programming resolution is 40ppm/K. Second order sensitivity temperature drift can be trimmed with TC2COLD and TC2HOT. The programming resolution is 2ppm/K<sup>2</sup> for TC2COLD and 0.6ppm/K<sup>2</sup> for TC2HOT. The second order can also be seen as third order correction since cold and hot sides are independently adjusted.

**Note:** for optimal performance over temperature, the first order sensitivity drift compensation (TC1ST) should not exceed ±250ppm/K.

#### 9.6 Offset temperature drift programming (OFFDR2C, OFFDR2H)

Offset temperature drift caused by the output amplifier can be compensated with these two parameters. This first order correction is done independently for temperatures over and below 25°C.

**Note:** Two additional parameters (OFFDR1C, OFFDR1H) are calibrated by Melexis to compensate for the offset temperature drift caused by the Hall element (before the variable gain amplifier). These parameters should not be adjusted on customer-side.

#### 9.7 Noise filter (NOISEFILT)

Setting this bit to 1 enables the noise filter, reducing noise and increasing response time.

#### 9.8 Identification code (ID)

48 bits programmable identification code.

#### 10 Self diagnostic

The MLX91208 provides self diagnostic features to detect internal memory errors and over- / under-voltage. Those features increase the robustness of the IC functionality, as they prevent the IC from providing erroneous output signal in case of internal or external failure modes.

Error	Action	Effect on Outputs	Remarks
Calibration Data CRC Error (at power up	Faultmode	High Impedance mode	Pull down resistive load => Diag Low
and in normal working mode)	i auitiiioue	Tilgit ilitpedance mode	Pull up resistive load => Diag High
Power On delay		High Impedance mode	5ms max in high impedance followed by
1 ower on delay			settling
Undervoltage Mode	IC is reset	High Impedance mode	300mV Hysteresis (typical)
Overvoltage detection	IC is reset	High Impedance mode	100mV Hysteresis (typical)

Table 10: Self diagnostic

#### 11 Application information

Please refer to our current sensor reference design guide for more application information: http://melexis.com/Assets/Current-Sensors-Reference-Designs-6187.aspx

#### 11.1 Low current measurement ±2-10A

Low currents can be measured by either using a multi-turn/multi-layer PCB where the current is allowed to flow several times under the sensor, or by adding a closed ferromagnetic shield around the current trace with a small air gap to concentrate the magnetic flux above the sensor.

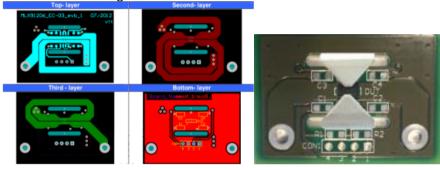


Figure 3: Low current applications with either multi-trace/multi-layer PCB (left) or closed shield (right).

#### 11.2 Medium current measurement up to ±50A

For medium currents, a single PCB trace can be used. The sizing of the PCB trace should take into account the current handling capability and the total power dissipation. The PCB trace should be thick and wide enough to handle the RMS current continuously.

A simple "U-shaped" ferromagnetic shield is often required to protect the sensor from cross-talk or external stray fields, if they cannot be cancelled-out by other means (peak-peak detection, etc.).

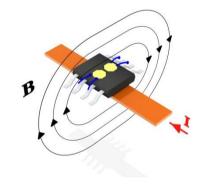


Figure 4: Medium current application on PCB

#### 11.3 High current measurement up to ±1000A

For high currents flowing in a bus bar, MLX91208 is typically assembled on a PCB lying immediately above the current conductor.

A ferromagnetic shield is usually added to protect the sensor from external fields and ensure good homogeneity of the magnetic flux, for optimal robustness against vibrations and mechanical tolerances.

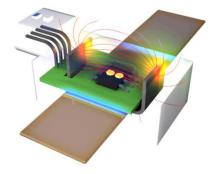


Figure 5: High current application on bus bar

### 12 Recommended Application Diagrams

#### 12.1 Resistor and capacitor values

Part	Description	Value	Unit
C1	Supply capacitor, EMI, ESD	100	nF
C2	Decoupling, EMI, ESD	2-10 (1)	nF
C3	Decoupling, EMI, ESD	47	nF
R1	Pull up or pull down resistor	6-100	kΩ

Table 11: Resistor and capacitor values

(1) 10nF is recommended for better EMC and ESD performance.

#### 12.2 Pull down resistor for diagnostic low

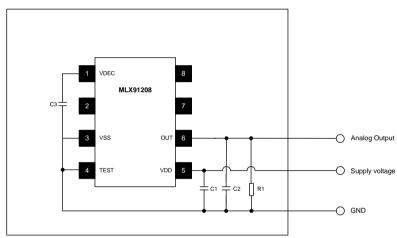


Figure 6: Diagnostic low

#### 12.3 Pull up resistor for diagnostic high

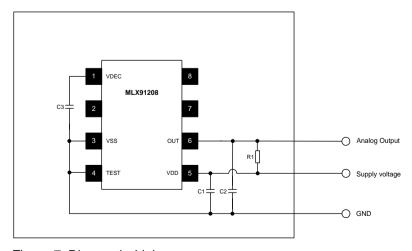
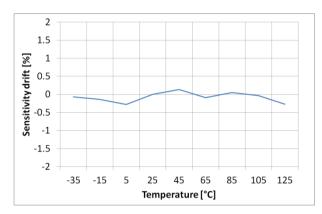


Figure 7: Diagnostic high



### 13 Typical performance



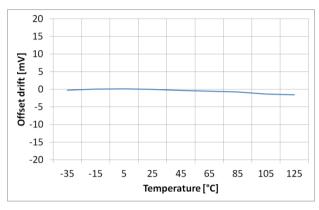


Figure 8: Thermal sensitivity drift.

Figure 9: Thermal offset drift.

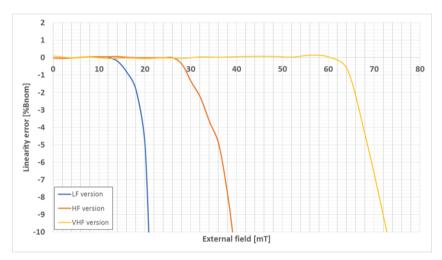


Figure 10: Linearity error for all versions.

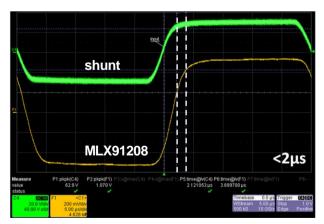






Figure 12: Response time with noise filter ON.



# 14 Standard information regarding manufacturability of Melexis products with different soldering processes

Melexis devices are qualified using state-of-the-art practices in accordance with automotive and environmental requirements.

Through qualifications, various soldering techniques are considered; please refer to "Soldering recommendations for Melexis products" for more information:

(http://www.melexis.com/Asset/Soldering\_Application\_Note\_and\_Recommendations\_DownloadLink\_5446.aspx).

For components normally soldered using Surface Mounted Device techniques (eg: Reflow process), Melexis has defined and qualified Moisture Sensitivity Level and Peak Temperature in accordance with the Jedec J-STD-020 standard. Delivered material is conditioned accordingly. Moisture Sensitivity Level and Peak Temperature information can be found on the label identifying the material.

In case you intend to use a reflow soldering process for through hole devices (Melexis' package codes: SA, UA, VA, VK, VM), please contact Melexis to verify your soldering process compatibility.

The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board.

Based on Melexis commitment to environmental responsibility, Europe legislations (Direction on the Restriction of the Use of Certain Hazardous substances, RoHS) and customer requests, Melexis has deployed Pb free leadfinish (typically Matte Tin) on all ASSP products.

For through hole devices (Melexis' package codes: SA, UA, VA, VK, VM) Trim&Form, please refer to "Trim & Form recommendations for Melexis products" for more information:

(http://www.melexis.com/Assets/Trim\_and\_form\_recommendations\_DownloadLink\_5565.aspx)

#### 15 ESD Precautions

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

ESD HBM robustness is 2kV on external pins according to AEC-Q100-002 REV-D.



### 16 Package information

#### 16.1 SOIC-8 Package Dimensions

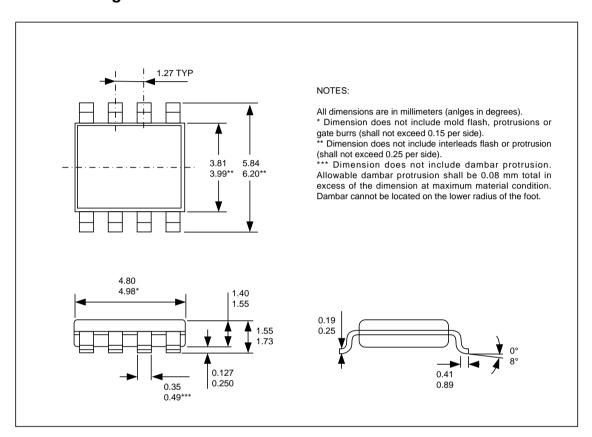


Figure 13: SOIC-8 Package dimensions

#### 16.2 SOIC-8 Pinout and Marking

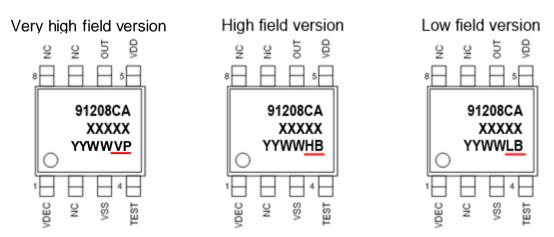


Figure 14: SOIC-8 Pinout and marking (Very High Field, High Field and Low Field version)

#### 16.3 SOIC-8 Hall plate position

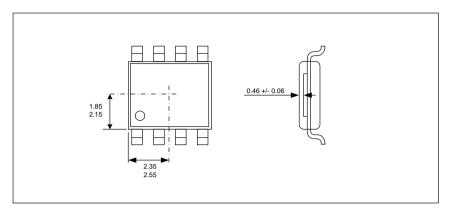


Figure 15: SOIC-8 Hall Plate positioning

#### 16.4 SOIC-8 IMC Position and magnetic sensitive direction

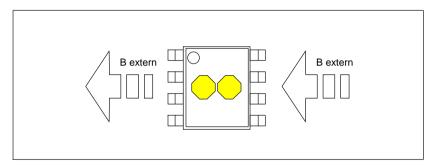


Figure 16: IMC position and geometry for low-field version

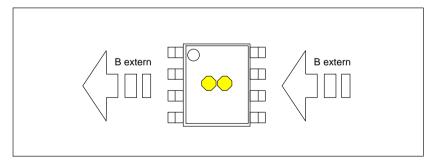


Figure 17: IMC position and geometry high-field version

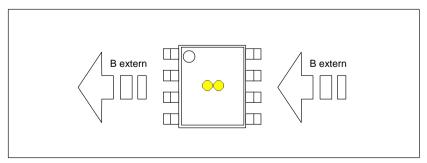


Figure 18: IMC position and geometry very high-field version

# MLX91208



## IMC-Hall<sup>®</sup> Current Sensor (Triaxis<sup>®</sup> Technology)

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Or for additional information contact Melexis Direct:

Europe, Africa, Asia: Phone: +32 1367 0495 E-mail: sales\_europe@melexis.com America:
Phone: +1 603 223 2362
E-mail: sales\_usa@melexis.com

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